F-8412   Identifier: Roland KAPLAN, et al.

Method and apparatus for imaging a mask on a substrate

The invention relates to a method for imaging a mask on a substrate in accordance with the features cited in the preamble to patent claim 1. The invention furthermore relates to an apparatus for performing the method.

5 Known from DE 39 10 048 C2 are such a method and an apparatus for performing said method. In this case it is an orientation system in photolithography with which a mask, a large area substrate, and a transfer system that contains an illumination unit and an optical unit can be oriented relative to one another, whereby structures of the mask can be transferred in small areas to the substrate.

10 During the transfer or imaging of the structure of the mask onto the substrate, a marking is applied thereto, and during scanning of the structures of the mask there is continuous orientation of the mask, relative to the area, with respect to the substrate. The mutual orientation of the mask and the substrate requires a certain complexity in terms of equipment, and in particular there are limits with regard to

15 the transfer speed and the attainable throughput due to time delays and inertia with the orientation system.

In the following, a template that is used for producing for instance printed circuit boards or flat screens and that is embodied as a film, emulsion mask, chrome mask, or the like will be called a mask. Such masks contain small structures such

1   F8412 SPEC {PC 5 }.wpd

as for instance tracks or in general geometric structures that are to be imaged or

copied onto a substrate. The typical size of such structures depends on the

application and in printed circuit board technology today is for instance 10 to 50

mm. In production of flat screens, structure sizes go down to 1 to 2 mm. The

5   tolerance when placing the structures, i.e., their positional accuracy, is clearly less

than the structure sizes themselves. Planar plate-shaped production elements or

production blanks are used for substrates. Thus for instance the production of

printed circuit boards requires multiple copying of very different structures on pre-

products, intermediate products, and the final product that forms the base for the

10   electronic components and the required electrical connections. The size of printed

circuit boards today is on the order of up to 600 x 800 mm^2, and there is talk of

multiuse applications due to the aforesaid pre-products, intermediate products,

and final products. Likewise, in the production of flat screens very similar

method steps occur, whereby clearly smaller dimensions must be observed for the

15   structure sizes and tolerance limits. The following tabular summary identifies

typical applications or substrates that are called blanks or blank elements in the

following:

1.   **Printed circuit boards:** Structuring of copper surfaces, structuring of

flexible printed circuit boards, cross-linking of solder resist or positive lacquer

2.   **Screen technology:** Lacquer image for structuring of metallic or non-conductive layers, cross-linking of color filters, creation of structures on flexible base materials such as e.g. film screens.

3.   **Microstructure engineering:** Creation of working copies, direct lighting

5   of large planar workpieces such as e.g. photovoltaic elements.

Planar flat substrates are generally quite thin and have a thickness of a few mm (micrometers) to several mm (millimeters) and are coated with a light-sensitive layer that is to be structured. The blank elements run through various production steps, whereby high temperature differences and other mechanical stresses can

10   occur. Such stresses can lead to permanent geometric changes. Thus, printed circuit boards for instance are composed of a plurality of layers of base films, and this method is often called pressing. The intermediate products that are composed or pressed in this manner have dimensional deviations that must be taken into account in the next production step so that for instance fine tracks for covering

15   through-contacts that are just as small can be made. Similarly, during production of screens the individual image elements must be contacted.

The distortions in the blank elements that occur in the production process fundamentally limit the minimum reasonably producible structures. In order for

3

the desired functions to be able to be realized by means of the structures of

different layers or blank elements, a minimum overlap must be ensured. For this

it is necessary that for a minimum structure size Z and taking into account a

production tolerance dZ, the associated counter-structure has the size Z , 2 x dZ.

5   This ensures that the structures overlap with a positional error dZ. On the other

hand, if the deviation between the structure or mask and the blank element is too

large, the structures associated with one another do not overlap any longer.

Furthermore, the problems inherent in optical imaging must be considered,

namely, positional accuracy and image sharpness. This means that the image of

10   the template or mask must be imaged as positionally accurate as possible on the

structure or the blank and the focus plane of the image must lie on the light-

sensitive layer of the substrate.

Starting at this point, the object of the invention is to embody both the method and

the apparatus such that precise imaging of the templates or masks and their small

15   structures on the substrate or blank element is attained with high functional

security, while taking into consideration the factors cited in the foregoing.

Creating precise copies of small structures on preferably large substrates and/or

blank elements should be possible with no problems. It should be possible to

image and/or create on the substrate the smallest possible structures for the mask

20   with high positional accuracy. Furthermore, the method and the apparatus should

F8412 SPEC {PC 5 }.wpd

be economical to employ and should enable high throughput.

This object is attained in terms of the method in accordance with the features cited in patent claim 1. The object is attained in terms of the apparatus in accordance with the features cited in patent claim 9.

5   The proposed method and the apparatus proposed for performing said method make possible the creation of precise copies of small structures on in particular large substrates and/or the creation of small structures on a distorted substrate with high positional accuracy and with a comparatively low complexity. In accordance with the invention, the mask, which represents the original in the

10   target dimensions, is corrected and/or distorted during the imaging by means of the optical unit or in the copying process, and thus the image of the mask is adapted on the substrate or the blank element to its individual distortions. Thus even the smallest structures are created on the distorted substrate with high positional accuracy, whereby in the following this process shall be called

15   distortion of the mask image.

In accordance with the invention, the image of the mask can be distorted individually in any direction and thereby corrected and in particular scaled such that distortions of the substrate are compensated. In accordance with the

invention, height and width of the mask image or its dimensions in the X-plane

and the Y-plane of the substrate are adapted to its distortions, if any. Furthermore,

compensation of higher orders can be performed in a preferred manner, whereby

the width of the image is a function of the height of the image or vice versa.

5   Thus, in particular a rectangular template or mask is transformed corresponding to

the established distortions of the substrate into a parallelogram or in general into a

trapezoid. The suggested distortion and/or transformation is inventively

individually determined for each blank element and/or for each partial area of it or

of the substrate. The correction and/or transformation parameters determined in

10   particular in accordance with the distortions of the substrate are used to correct the

mask image during the imaging or copying process. The distortion of the mask

image and/or the orientation is performed in accordance with the invention by

overlapping and/or continuous joining of individual images, each of which is

smaller than the overall image. In the framework of the invention, the distortions

15   are performed in particular by translation and/or rotation and/or shearing and/or

direction-independent scaling. The method and/or the apparatus are not limited to

certain structure sizes, nor must method-related tolerance limits be observed. In

addition, there are no limits in terms of the size or dimensions of the substrate.

Both the mask and the substrate preferably have mechanical apparatus or

20   markings so that the image of the mask or template is imaged on the substrate or

blanks as positionally accurate as possible and an exact orientation is attained. In

the most simple case, reference bores can be provided for this, by means of which

the position of the mask and the blank element are fixed individually by means of

pins. For very thin blank elements and the large distortions that occur with them,

5   this is not useful since the substrate could undulate. Therefore, for very thin blank

elements, markings are applied, for instance fiduciary points or orientation marks

or alignment markings that can be evaluated using associated optics and a camera

system. Information about the position of the mask and/or the position of the

blank element is determined by measuring such markings. The corresponding

10   measurement values are used to calculate the distortion, such as e.g. the

displacement or the rotation of the blank element. In the inventive method and

the apparatus suggested for performing the method, simple optical components are

used and the mask is inventively distorted, and is copied, taking into consideration

the detected distortions of the blank element, at the required correct position of the

15   blank element. Furthermore, in accordance with the invention, the focus plane of

the image is imaged on the light-sensitive surface of the substrate for obtaining an

optimum image, in particular with correct structure size, edge quality and edge

slope on the blank element. For this, a focusing apparatus is provided by means

of which the length of the optical path between the mask and the blank element is

20   rendered variable without the imaging scale being affected. The focusing

apparatus is usefully a component of the optical element.

In one preferred embodiment of the invention, at any time and/or just one small

part of the mask is imaged by means of the optical unit on the blank element.

The overall image on the blank element is created by relative movement between

mask and substrate on the one hand and the optical unit on the other hand, which

5   is also called imaging optics. It is particularly important that the position of the

mask relative to the substrate is not changed during the exposure. The mechanical

movement between the optical unit, preferably also the illumination unit, on the

one hand, and the mask and the substrate on the other hand is performed

advantageously as slowly as possible, whereby the (quite high) speeds and

10   accelerations that are fundamentally possible with the mechanical system are not

used in order to keep the forces on the optical components and the mask and

substrate as low as possible. The mechanical system preferably contains a cage by

means of which the mask and the substrate are arranged fixedly and securely to

one another in the manner necessary. For one thing, the goal is an image field that

15   is as large as possible in order to keep the required mechanical movements or cage

movements for composing the overall image small. For another thing, a small

image field is desired so that the inventive distortion, in particular scaling, can be

performed. The small image field required for the distortion is moved relatively

rapidly over the mask and the blank element by means of the optical unit. For this

20   purpose, a light scan is advantageously provided perpendicular to the direction of

movement of the mechanical system or the cage. The movement of the

8

illuminated area on the mask, hereafter called the illumination dot, is composed of

two movements. In a useful manner, the mechanical system or the cage moves

relative to the optical unit comparatively slowly, specifically on the order of 0.1 to

1 m/sec. In contrast, the illumination dot moves comparatively rapidly relative to

5   the optical unit or the imaging optics, specifically on the order of 1 to 10 m/sec.

In one preferred embodiment of the invention, the image is composed of a

plurality of partial images, whereby the following is taken into account for the

abutting surfaces on the edges of the partial images. If the partial images do not

join together precisely, gaps occur in the overall image, which is then unusable.

10   On the other hand, if the partial images overlap, there can be over-exposure in

those areas that are imaged multiple times, whereby the structure sizes can deviate

from the target value in multiply exposed areas of the light-sensitive layer of the

substrate. Therefore, in accordance with the invention the exposure intensity is

reduced in edge areas in which partial images overlap. Advantageously used for

15   this is an illumination unit or a light source that has at least an approximately

Gauss-shape beam profile and/or light intensity distribution at least approximately

corresponding to a Gaussian distribution curve.

The inventive method and the apparatus proposed for performing said method

make it possible to image the mask on the substrate as is and/or taking into

account distortions of the substrate or of the blank element, whereby the imaging

optics or the optical unit together with the illumination unit are moved relative to

the mask and the substrate. In a preferred manner the image field of the imaging

optics is smaller than the entire image and yields a predetermined number of

5   individual images. The entire image of the mask is thus composed of individual

images. Each individual image is moved in the X/Y-plane on the substrate by

means of active displacing elements in the imaging optics or the optical unit. By

controlling the aforesaid displacing elements appropriately, the overall image can

be composed of the individual images such that the required distortion is achieved

10   in the overall image.

The cited distortion is calculated and/or predetermined by measuring marks, in

particular alignment marks, on the mask and the substrate or by assigning

distortion values, whereby advantageously a combination of measured values and

assigned values can be performed. Based on the cited measurement, relative

15   positions of markings of the mask to markings of the substrate are determined.

For the inventive correcting method, the image is distorted such that the markings

of the substrate are imaged. In this case the mask and/or the substrate can be

corrected.

In a preferred manner, image distortion and/or orientation is performed by

F8412 SPEC {PC 5 }.wpd

overlapping and/or continuous joining of individual images that are each smaller

than the overall image of the mask. The distortions are performed in particular by

translation, rotation, shearing, or direction-independent scaling. Advantageously,

at least nearly constant intensity is defined across the mask surface in the temporal

5   mean by soft shielding of the illumination intensity and/or overlapping the

individual illumination dots. The illuminated area of the mask is imaged onto the

substrate using the optical unit or imaging optics, whereby the imaging represents

the structure of the mask with the intensity course of the illumination on the

substrate and/or nearly constant image intensity in the temporal mean is attained

10   on the substrate. In a preferred manner a Gauss-like intensity distribution of the

illumination dot is provided, in particular by using a laser for the light source.

Furthermore, in the framework of the invention the movement of the illumination

dot on the mask is composed of two movements, whereby advantageously a rapid

scanning movement of the illumination and/or the illumination dot occurs and a

15   comparatively slower movement of the mechanical unit, in particular a cage,

occurs, to which mechanical unit the mask and the substrate are arranged aligned

and fixed. Furthermore provided are a correction unit and a control unit that

controls the correction unit depending on the position of the illumination dot on

the mask and that is in particular integrated into the optical unit. The combined

20   movement of the illumination dot on the mask is in particular taken into account.

11

In one preferred embodiment, control of the illumination intensity on the mask

occurs by controlling the illumination unit or associated controllable damping

elements. This can in particular occur for pulsed lasers by varying the pulse rate.

In addition, control of the illumination intensity can be performed as a function of

5   the position of the illumination dot on the mask. Additionally or alternatively, the

illumination intensity can be controlled as a function of the speed of the

mechanical unit or the cage. This advantageously attains at least nearly constant

intensity distribution in the temporal mean on the mask, even if the speed of the

mechanical unit is not constant.

10   Advantageously, the optical path is calibrated, whereby, with a light source of the

illumination unit available or provided for this, a reference structure is imaged on

a camera preferably fixed on the table of the mechanical unit, which camera is

called an alignment camera. Furthermore, alignment of the light path is

performed in a useful manner, specifically using the active elements in the optics

15   path and/or the optical unit. Calibration of the optics measuring devices on the

reference mark and camera of the table takes place.

In another embodiment of the invention, the optical unit contains two lenses or

lens systems in a so-called 4f arrangement, whereby the mask is arranged in the

front focal point of the first lens system. The substrate is arranged in the back

focal point of the second lens system. The ray path in front of the first lens system

or after the second lens system is point-reflected, especially using a retroreflector.

Furthermore, it has proved advantageous to combine the imaging optics or the

optical unit with a correction unit such that the image is displaced perpendicular

5   to the optical axis in the image plane. For this, the following measures are

provided individually or in combination, depending on specific requirements. The

ray bundle is displaced parallel to the optical axis by means of a plane-parallel

plate by tilting perpendicular to the optical axis. Furthermore, a mirror can be

provided that can be tilted perpendicular to the entering and exiting ray bundle.

10   Furthermore, a retroreflector can be provided that is displaceable perpendicular to

the optical axis. In addition, for calibrating the optics path, the light path can be

lengthened or shortened by means of the imaging optics, specifically preferably by

moving the aforesaid retroreflector. In this way in a useful manner the image

plane can be imaged precisely on the substrate surface. The setting of the image

15   plane can be adjusted either statically by providing target values or dynamically by

positional measurement of the substrate surface.

A plurality of preferably parallel ray paths can be used in a preferred manner for

enhancing the throughput of the system or the apparatus. In this case, a plurality

of illumination dots are created on the mask by means of the illumination unit,

20   which illumination dots are imaged by a plurality of optical units and/or imaging

13   F8412 SPEC {PC 5 }.wpd

and correction units on the substrate. In addition, copying of a mask can occur in

an advantageous manner in that a plurality of parallel ray paths are created with a

plurality of illumination dots on the mask. Also, a mask can be copied in the

framework of the invention in that a plurality of parallel ray paths are created on

5   the substrate by means of a beam splitter in the optical unit.

Special designs and further developments of the invention are provided in the

subordinate claims and in the following description of the figures.

The invention is explained in greater detail in the following using the exemplary

embodiments depicted in the drawings, without this constituting a restriction.

10   Fig. 1   depicts the principle of a correction or image distortion by joining of

            individual images;

Fig. 2   is a schematic representation of an exemplary embodiment of the

            invention;

Fig. 3   is a schematic representation of an apparatus for distorted imaging of a

15   mask;

Fig. 4   depicts the principle for vector addition of the illumination position from

the position of the mechanical unit and the illumination unit;

Fig. 5   is a schematic representation of overlapping illumination dots of an

illumination unit with Gaussian intensity distribution in one direction in

5   space;

Fig. 6   is an exemplary embodiment of an optical unit with two lens systems in a

so-called 4f arrangement with a downstream retroreflector;

Fig. 7   is a schematic representation of an illumination unit for generating two

illumination dots on the mask;

10   Figs. 8 and 9 are schematic arrangements for simultaneous copying of masks or

for multi-imaging.

Fig. 1 illustrates the principle of image distortion by joining individual images.

One partial area of the mask 1 is imaged on the substrate 2, whereby an

illumination dot 3 is created on the mask 1 by means of an illumination unit and is

15   imaged on the substrate 2 as an individual image 5. The entire image is composed

of overlapping individual images 5, whereby each individual image is an

F8412 SPEC {PC 5 }.wpd

undistorted 1:1 image of the mask or of the associated illumination dot. The

distortion of the overall image occurs through a displacement of the individual

images 5 on the substrate 2 by a correction vector 4. The distortion of the

substrate 2 is calculated by measuring markings, in particular alignment marks, on

5   the mask 1 and the substrate 2 or by specifying distortion values, whereby it is

useful that a combination of measurement values and defined values can be used.

Based on the measurement, the relative positions of mask marks to substrate

marks are determined, whereby in accordance with the correction method the

image is distorted such that the mask marks are imaged on the cited substrate

10   marks. The mask 1 or the substrate 2 and if necessary both can be corrected. The

cited displacement effects an indistinctness in the overlapping area 6, whereby the

maximum offset of two adjacent individual images 5 is provided according to the

tolerable indistinctness and the size of the overlapping area 6.

Fig. 2 is a schematic representation of an exemplary embodiment of the apparatus

15   whose mechanical unit contains a cage 7 by means of which the mask 1 and the

substrate 2 are spaced and securely fixed to one another. Arranged separately

from the mechanical unit or the cage 7 are an illumination unit 8, an optical unit 9,

a mask camera 10, and a substrate camera 11. Furthermore, an alignment camera

12 and a reference mark 13 are securely fixed to the cage 7. An X-drive 15 and a

20   Y-drive 16 are provided for moving the cage 7 in the X/Y plane. The cage 7 and

F8412 SPEC {PC 5 }.wpd

the aforesaid components affixed thereto are inventively relatively movable

relative to the other components such as in particular the illumination unit 8,

optical unit 9, which are mounted fixed to one another and are in a defined

geometric arrangement to one another. Thus the mask 1, the substrate 2, and the

5   alignment camera 12 are arranged, with the cage 7, relatively movable to all other

components of the apparatus.

The mask 1 is rear illuminated in a partial area, the cited illumination dot 3, by

means of the illumination unit 8. This partial area or illumination dot 5 is imaged

undistorted and unenlarged on the substrate 2 via the optical unit 9. The optical

10   unit 9 contains an imaging and correction unit and is disposed in the optical path

between the mask 1 and the substrate 2. The individual image is displaced on the

substrate 2 in the X/Y plane by means of the aforesaid correction unit. The

positions of registration marks 13 are determined on the mask 1 and the substrate

2 by means of the camera and downstream image processing software of an image

15   processing system for determining the distortion thus attained. The control data

for the aforesaid imaging and correction unit are recalculated from the positions of

the registration marks 14.

For aligning the optics path, the cage 7 is moved into a position in which the

reference structure or reference mark 13 is rear illuminated by the illumination

unit 8. The reference mark 13 is imaged on the alignment camera 12 by means of

the optical unit 9, which forms the imaging and correction unit. By controlling

the correction unit of the optical unit appropriately, the image of the reference

mark 13 is imaged onto a standard position on the alignment camera 12. Thus the

5   coordinate system of the mask 1 is related to the coordinate system of the

substrate 2. The control data obtained in this manner are taken into account as

offset values in the correction calculation for the later mask imaging. Then the

reference structure or reference mark 13 is moved under the mask measurement

camera 10 and the position of the reference mark 13 is measured. This determines

10   the position of the mask camera 10 relative to the reference mark 13. Analogous

to this, the substrate camera 11 is moved, whereby especially the position of the

CDC chip in the alignment camera 12 is used for reference mark. The thus

determined positions of the mask camera 10 and substrate camera 11 are taken

into account as offset values during the measurement of alignment marks on the

15   mask and/or masks or on the substrate and/or substrates.

Fig. 3 is a schematic overview of an apparatus for distorted imaging of the mask

1. Provided as light source for the aforesaid illumination unit is a laser 17 that

preferably has a mean output of 1 to 10 W in a normal wave range for exposure of

printed circuit boards in the range of 350 to 400 nm. The illumination diameter

20   required for the application is adjusted with a beam expansion unit 18. The

F8412 SPEC (PC 5).wpd

expanded laser beam is moved perpendicular to the surface of the mask 1 by

means of a scanning device 19. As already explained, the mask 1 and the

substrate 2 are held securely to the cage 7 of the mechanical unit. Arranged in the

optical path between the mask 1 and the substrate 2 is the optical unit 9 with

5   active elements for positional correction and for imaging the illumination dot 3 on

the substrate 2. The optical unit 9 contains a plane-parallel plate 20 with a 2-axis

tilt drive 21, a lens system or a lens 22, a scan mirror 23 with associated 2-axis tilt

drive 24, a second lens system 22, and a retroreflector 25 with associated XYZ

drive 26. The image field of the image is provided large enough that the entire

10   illuminated area of the mask 1 is imaged on the substrate 2 in every position of the

illumination scan. The cage 7 is movable by means of the aforesaid X/Y drive

with a positional regulator 27 in the manner necessary independent of the

illumination unit 8 and the optical unit 9 relative thereto. The positional control

or regulation of the cage 7, the active elements 20, 23, 25 of the optical unit, the

15   laser 17, and the scanning device or the illumination scanner 19 are connected to a

computer system 28 and/or are controlled by means of the computer system 28.

For determining the measurement data required for the corrections, an image

processing system 29 is allocated to or integrated in the computer system 28,

whereby the aforesaid cameras are connected to the image processing system 29.

20   The positions of the registration marks in the camera images are calculated by

means of the image processing system 29 and with the detected cage position their

19   F8412 SPEC {PC 5 }.wpd

absolute position on the mask 1 and/or the substrate is calculated. A reference

mark 13 is arranged on the plane of the mask 1 of the cage 7 and the alignment

camera 12 is arranged on the plane of the substrate 2. The reference mark 13 is

imaged by means of the optical unit on the alignment camera 12. In this manner

5   the aforesaid active elements 20, 23, 25 or the optical unit are realigned as needed.

The entire computer system 28 is controlled using an operator's computer 13, to

which a suitable operator interface, in particular on a screen or monitor, is

allocated.

In an advantageous manner, the illumination intensity on the mask 1 is controlled

10   by controlling the illumination source, in particular the laser 17, via the computer

system 28. Thus, for instance with a pulsed laser 17, the intensity is influenced by

varying the pulse rate or in a CW laser by controllable damping. The system data,

in particular the position of the illumination dot on the mask or the speed of the

table or the cage 7, are available to the computer system 28 at all times. This is

15   how the intensity is controlled depending on the aforesaid and/or other

parameters. In addition, the intensity is adapted to different speeds of the cage 7

such that there is the defined and/or desired intensity distribution in the sum on

the mask 1. This ensures that the exposure can be performed during the

acceleration and/or braking phase of the cage 7.

F8412 SPEC {PC 5 }.wpd

The inventive apparatus has the following structure.

1.   Illumination path with light source, in particular laser 17, expansion optics

      or beam expander 18, illumination scanner or scanning device 19.

2.   A mask holder that is adapted to various mask types, such as chrome

      masks, emulsion masks, or films.

3.   Optical unit 9 with input optics, X/Y scanner, output optics, and focus

      device.

4.   Substrate holder that is adapted to various blank elements, such as thin

      films, continuous films, printed circuit boards, or glass substrates.

As Fig. 4 illustrates, the position of the illumination dot 3 on the mask 1 is

determined by the X/Y position of the cage and the position of the illumination

scanner 19. Strip-wise illumination of the mask 1 is performed by combining a

rapid scanning movement 32 with a relatively slow cage movement 31. The

optical unit 9 is designed such that it can image the illumination dot 3 in all

scanning positions on the substrate 2. The movement of the illumination dot 3 is

inventively set such that the illuminated areas overlap. Nearly constant intensity

distribution across the surface of the mask to be illuminated is achieved in the

temporal mean by this overlapping together with the Gauss-like intensity

distribution. Soft shielding of the illumination intensity is provided, whereby the

illumination intensity in the edge area of the illumination dot 3 is less by a

predefined amount than in the center of the illumination dot 3, preferably

corresponding to the Gauss-like intensity distribution of the laser. The

illuminated area of the mask 1 is imaged using the optical unit 9 on the substrate,

5   whereby the image is the structure of the mask 2 with the intensity course of the

illumination. Thus in the temporal mean an image intensity that is at least nearly

constant is attained on the substrate 2.

The intensity of the illumination is controlled by the computer system. This can

occur by controlling the illumination source or controllable damping elements, for

10   instance by means of a pulsed laser by varying the pulse rate. In addition, the

illumination intensity is controlled as a function of the position of the illumination

dot 3 on the mask 1. Furthermore, in the framework of the invention the intensity

of the illumination is defined as a function of the speed of the cage, so that a

constant intensity distribution is attained in the temporal mean on the mask 1,

15   even if the speed of the cage is not constant. Apart from varying the pulse rate in

pulsed lasers, in particular in a CW laser the intensity of the illumination can be

defined by controllable damping. The system data, in particular the position of

the illumination dot 3 on the mask 1 or the speed of the cage or its table are

available to the computer system at all times. This is how it is possible to control

20   the intensity of the illumination as a function of other parameters. The intensity is

usefully adapted to different speeds of the cage such that the desired intensity

distribution is in the sum on the mask 1. Thus advantageously exposure can be

performed during the acceleration and/or braking phase of the cage.

The soft shielding of the illumination intensity and overlapping of the illumination

5   dots is provided in particular by means of a laser whose beam intensity has a

Gaussian profile perpendicular to the beam direction. Advantageously, the

illumination intensity is controlled, and thus the light intensity is adjusted, by

varying the pulse rate of the pulsed laser. The rapid movement of the illumination

dot 3 compared to the cage movement is preferably produced by deflection on a

10   scanning mirror of the illumination scanner 19.

For the inventive correction method, the image on the substrate is distorted such

that the mask marks are imaged on the substrate marks, whereby it is unimportant

whether the mask 1, the substrate 2, or both are corrected. These different

correction options require that the correction vector Dx and Dy are a function of

15   the position of the illumination dot (xb, yb) on the mask 2 according to the

following equation:

$$Dx = f_1(x_b, y_b)$$

$$Dy = f_2(x_b, y_b)$$

The illumination position is added vectorally from the cage position and the scan

position. A correction device and control are used such that depending on the

position of the illumination dot 3 on the mask 1, the correction unit of the optical

unit 9 is controlled appropriately, whereby in particular the movement explained

5   in the foregoing is taken into account. The correction unit is designed such that

both the rapid scanning movement and the comparatively slower cage movement

31 can occur. Controlling the correction device ensures that the position of the

illumination dot is determined from the position of the table or cage and the

scanning position. From these positions, preferably in real time and taking into

10   account the provided corrections, the control signals for the correction unit are

calculated and produced, specifically advantageously in accordance with the

following equation:

$$= \qquad +$$

In order to ensure long-term stability of the apparatus, the mechanics unit or the

15   cage 7 contains the reference mark 13 and the alignment camera 12. The

reference mark 13 is arranged on the mask plane and the alignment camera 12 is

mounted on the substrate plane. By imaging the reference structure or reference

mark, in particular with the exposure source contained in the illumination unit 8

or alternatively with a separate exposure source, on the fixed alignment camera

12, calibration of the optics path is achieved in a preferable manner. Realignment

of the optics path between the mask 1 and the substrate 2 occurs advantageously

5   using one of the active elements of the optical unit 9. The calibration of the optics

measurement devices is performed advantageously by means of the reference

mark 13 and the table camera and/or the alignment camera, which is arranged on

the substrate plane. The cage position in the X/Y plane is measured continuously

using a measurement system. The aforesaid cameras and the measurement system

10   are connected to the computer system by means of which the measurement values

are evaluated and the drives of the cage and the correction devices are controlled

corresponding to correction values and/or correction vectors thus obtained.

Advantageously, a desired image distortion and orientation is performed by

overlapping or continuous joining of individual images that are smaller than the

15   overall image. Special cases for the distortions inventively provided for

correction are translation, rotation, shearing, and direction-independent scaling.

Advantageously, nearly constant intensity is attained across the mask surface in

the temporal mean through so-called soft shielding of the illumination intensity

and overlapping the illumination dots 3. The illuminated area or illumination dot

20   3 of the mask is imaged onto the substrate 2 using the imaging optics. The image

25

thus produced is the structure of the mask with the intensity course of the

illumination. Advantageously at least nearly constant intensity is attained in the

temporal mean on the substrate 2. Advantageously, used for the light source is a

laser whose beam intensity has a Gauss-like profile perpendicular to the beam

5 direction. In addition, in a preferred manner the light intensity can be defined in

particular by varying the pulse rate of a pulsed laser. The rapid movement of the

illumination dot on the mask 1 is produced in particular by deflection by means of

a scanning mirror of the illumination scanner.

Fig. 5 illustrates the overlapping for instance in one direction in space of

10 illumination dots 3, whereby the basis for one illumination is Gaussian profiles or

a Gaussian intensity distribution. Due to the defined overlapping of the curves,

the cumulative intensity 34 on the mask is sufficiently constant up to a residual

ripple. The smaller the residual ripple desired, the greater the defined overlapping

area 6 of the Gaussian profile. The overlapping area changes when there is a

15 correction of the individual images 5, that is, a displacement in the X/Y plane.

The change in the overlapping area 6 is small relative to the absolute size. Thus

there is only a slight change in the residual ripple, so that the light intensity 35 on

the substrate is at least nearly constant. It has been established that the image on

the substrate is the structure of the mask with the intensity course of the

F8412 SPEC {PC 5 }.wpd

illumination. Thus a nearly constant image intensity in the temporal mean is attained on the substrate.

Fig. 6 illustrates an exemplary embodiment of the optical unit containing two lens systems 22, each of which can also be embodied as individual lenses. The two

5   lens systems 22, with a retroreflector downstream in the light path, form a so-called 4-fold arrangement. With such an arrangement, a nearly 1:1 individual image 5 is produced on the substrate 2 by the object or the illumination dot 3 of the substrate 1 . Such an image is undistorted and not point-mirrored. By displacing the retroreflector 25 in the Y direction, the image plane is adjusted onto

10   the substrate 2. In combination with the measurement system, with which the position of the substrate surface is determined in the Z direction, in the framework of the invention the image plane can be adjusted once or readjusted continuously. Provided in the optical path are three active elements that are contained individually or in various combinations, in particular in the optical unit,

15   depending on application. The image field and/or the image in the X/Y plane is displaced with at least one, preferably all of the active elements. Thus the image field is displaced by tilting the axis-parallel plate 20 perpendicular to the optics axis. The image field is also displaced by tilting the scanning mirror 23 perpendicular to entering and reflected beam by means of the 2-axis tilt drive 21.

In addition, the image field is displaced by displacing the retroreflector 25 in the

X/Z plane.

Furthermore, advantageously the illumination speed, and thus the throughput of

the apparatus, can be increased in that multiple imaging and correction units are

5   provided in parallel. Multiple illumination dots are produced on the mask that are

imaged by multiple imaging and correction units on the substrate. As Fig. 7

illustrates, for this the illumination unit is embodied such that at least two

illumination dots 3 are produced on the mask. The correction values or vectors 4

are defined independent of one another in a preferred manner by means of the two

10   separate optical units 9.

Figs. 8 and 9 illustrate arrangements for simultaneous copying of the masks. At

least two, when required also more, imaging and correction units are arranged

such that simultaneous reproduction of one mask 1 is performed on one or more

substrates 2. Fig. 8 provides the example of two-fold imaging, whereby two

15   illumination dots 3 are present due to two parallel ray paths. In accordance with

Fig. 9, a single illumination dot 3 is produced on the mask 1 and the optical unit

contains a beam splitter 37 by means of which two parallel ray paths are produced

by means of the optical unit 9 for producing two individual images 5. It is

understood that in the framework of the invention a larger number of individual

images can be produced analogously instead of two individual images.

Legend

1	Mask
2	Substrate/blank element
3	Illumination dot
4	Correction vector
5	Individual image
6	Overlapping area
7	Mechanical unit/cage
8	Illumination unit
9	Optical unit/imaging and correction unit
10	Mask camera
11	Substrate camera
12	Calibration camera
13	Reference mark
14	Registration mark
15	X drive
16	Y drive
17	Laser
18	Beam expander unit
19	Illumination scanner
20	Displacement element/plane-parallel plate
21	2-axis tilt drive of 20
22	Lens system/lens
23	Displacement element/scanning mirror
24	2-axis tilt drive of 23
25	Displacement element/retroreflector
26	XYZ drive of 25
27	Position regulator for cage drive
28	Computer system
29	Image processing system
30	Operator's computer with operator interface
31	Cage movement
32	Scanning movement
34	Cumulative intensity on the mask
35	Cumulative intensity on the substrate
36	Mirror
37	Beam splitter

F8412 SPEC {PC 5 }.wpd